

## **AMENDMENTS TO THE CLAIMS**

The following listing of claims will replace all prior versions and listings of claims in the application.

### **LISTING OF CLAIMS**

1. (cancelled).

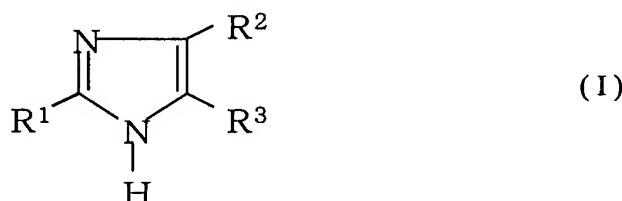
2. (cancelled).

3. (currently amended) An organic bistable memory device comprising an organic bistable element and a limiter, wherein

the organic bistable element comprises an organic thin film bistable body having a single layer structure interposed between a first electrode and a second electrode, and

the limiter limits current, which flows in either a positive bias side or a negative bias side to a given value in writing information into the organic bistable element,

the organic thin film consisting essentially of an organic compound represented by formula (I):



wherein, in R1, R2, and R3,

one or two of them each independently represent an electron-donating group selected from the group consisting of -H, -NH<sub>2</sub>, -NHR, -NR<sub>2</sub>, -SR, -X, -CX<sub>3</sub>, -OH, -OCH<sub>3</sub>, -OR and -R wherein R represents a straight chain or branched chain alkyl group having 1 to 24 carbon atoms in which one or at least two methylene groups in the alkyl group are optionally substituted by a substituent of -O-, -S-, -CO-, -CHW-, wherein W represents -F, -Cl, -Br, -I, -CN or -CF<sub>3</sub>, -CH=CH-, or -C≡C-, provided that a plurality of said substituents are not adjacent to each other, and X represents -F, -Cl, -Br, or -I and

the remaining group or groups of R<sup>1</sup>, R<sup>2</sup>, and R<sup>3</sup> each independently represent an electron-receiving group selected from the group consisting of -CN, -NO<sub>2</sub>, -COR, -COOH, -COOR and -SO<sub>3</sub>H.

4. (cancelled).

5. (cancelled).

6. (original) The organic bistable memory device according to Claim 3, further comprising a substrate and either the first electrode or the second electrode is stacked in contact with a top of the substrate.